



PHOTONICS RESEARCH GROUP

Navolchi Telco 8 Oct 2012

Summary

MEMS-based steerable grating couplers

New structures arrived – post-processing completed

Lateral movement now clearly demonstrated (+/-1um)

Axial movement : not yet

Electrically injected silicon-quantum dot amplifiers

Delay in processing

To start next week

Optimization of SiN-etching process

To be combined with embedded quantum dots

Characterization of 1D photonic crystal structures (Silicon)

Next step: combine with quantum dots

SiN etching

Double SiN layer with embedded QDOTS

High Temperature first

Then Qdots

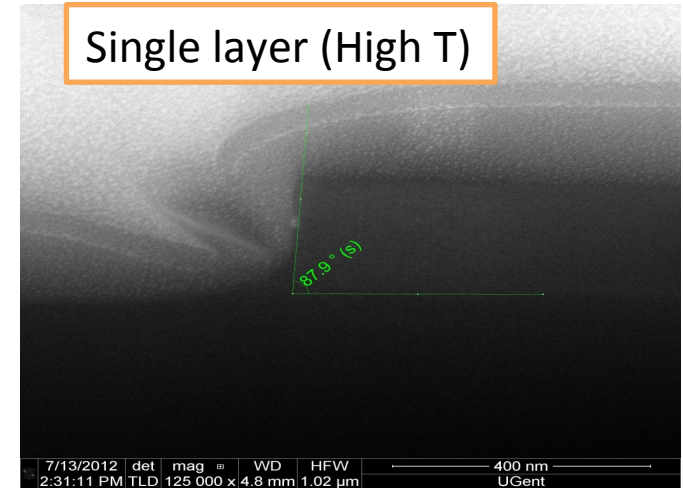
The Low temperature

Issue: low temperature layer etches very different

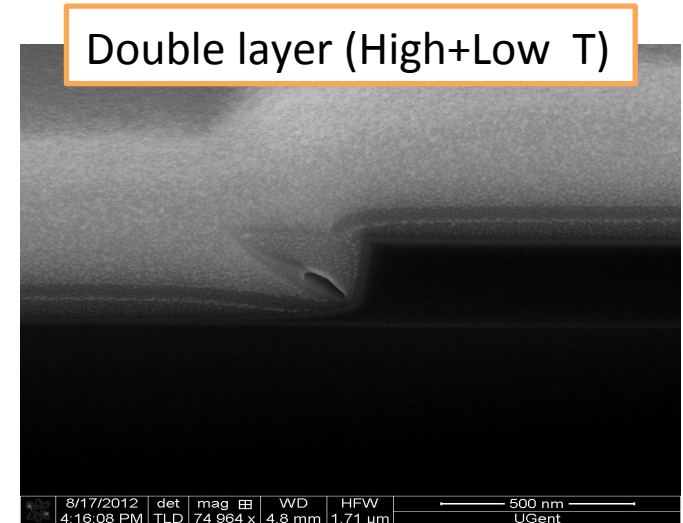
Initially: Step of $> 500\text{nm}$

Optimized process: no step !!!

Single layer (High T)



Double layer (High+Low T)



1D Photonic Crystal cavities

Fabrication using 193nm DUV

Quality factor >50.000

(Oxide embedded !!)

Next step: QDots on top

